

PENTA TVS/ZENER ARRAY FOR ESD AND LATCH-UP PROTECTION

This 5 TVS/Zener Array family have been designed to Protect Sensitive Equipment against ESD and to prevent Latch-Up events in CMOS circuitry operating at 5V, 12V, 15V and 24V. This TVS array offers an integrated solution to protect up to 5 data lines where the board space is a premium.

SPECIFICATION FEATURES

- 350W Power Dissipation (8/20 μ s Waveform)
- Low Leakage Current, Maximum of 5 μ A at rated voltage
- Very Low Clamping Voltage
- IEC61000-4-2 ESD 20kV air, 15kV Contact Compliance
- Industry Standard Surface Mount Package SOT23-6L
- 100% Tin Matte Finish (RoHS Compliant)
- Lead free in comply with EU RoHS 2002/95/EC directives.
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- Personal Digital Assistant (PDA)
- SIM Card Port Protection (Mobile Phone)
- Portable Instrumentation
- Mobile Phones and Accessories
- Memory Card Port Protection

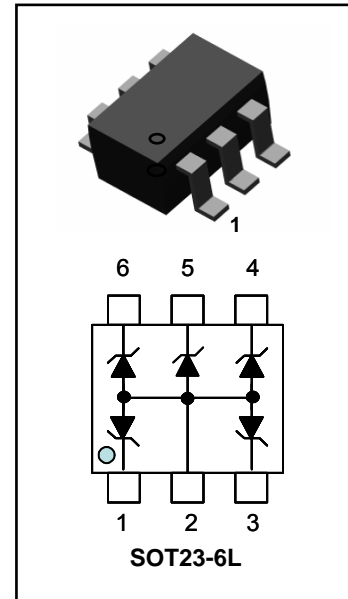
MAXIMUM RATINGS (Per Device)

Rating	Symbol	Value	Units
Peak Pulse Power (8/20 μ s Waveform)	P _{pp}	350	W
ESD Voltage (HBM)	V _{ESD}	>25	kV
Operating Temperature Range	T _J	-50 to +125	°C
Storage Temperature Range	T _{stg}	-50 to +150	°C

ELECTRICAL CHARACTERISTICS (Per Device) T_j = 25°C

PJSM S05C

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				5	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA	6			V
Reverse Leakage Current	I _R	V _R = 5V			5	μ A
Clamping Voltage (8/20 μ s)	V _C	I _{pp} = 5A			9.5	V
Clamping Voltage (8/20 μ s)	V _C	I _{pp} = 24A			13	V
Off State Junction Capacitance	C _j	0 Vdc Bias f = 1MHz Between I/O pins and pin 2			200	pF
Off State Junction Capacitance	C _j	5 Vdc Bias f = 1MHz Between I/O pins and pin 2			110	pF



Device	Marking Code
PJSM S05C	MD5
PJSM S12C	MA2
PJSM S15C	MA5
PJSM S24C	MB4

**ELECTRICAL CHARACTERISTICS (Per Device) T_j = 25°C****PJSMS12C**

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				12	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA	13.3			V
Reverse Leakage Current	I _R	V _R = 12V			5	μA
Clamping Voltage (8/20μs)	V _c	I _{pp} = 5A			17	V
Clamping Voltage (8/20μs)	V _c	I _{pp} = 15A			21	V
Off State Junction Capacitance	C _j	0 Vdc Bias f = 1MHz Between I/O pins and pin 2			90	pF

PJSMS15C

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				15	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA	16.7			V
Reverse Leakage Current	I _R	V _R = 15V			5	μA
Clamping Voltage (8/20μs)	V _c	I _{pp} = 5A			22	V
Clamping Voltage (8/20μs)	V _c	I _{pp} = 12A			27	V
Off State Junction Capacitance	C _j	0 Vdc Bias f = 1MHz Between I/O pins and pin 2			70	pF

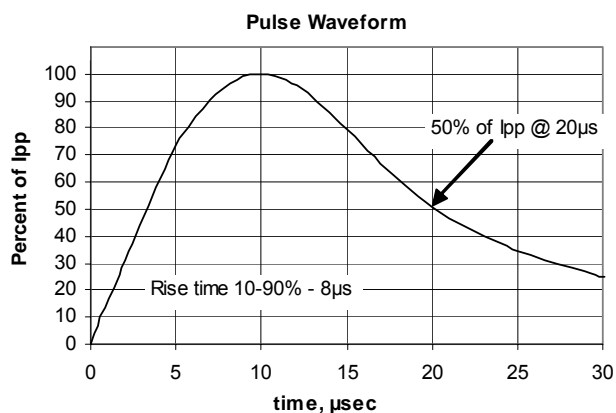
PJSMS24C

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				24	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} = 1mA	26.7			V
Reverse Leakage Current	I _R	V _R = 24V			5	μA
Clamping Voltage (8/20μs)	V _c	I _{pp} = 5A			35	V
Clamping Voltage (8/20μs)	V _c	I _{pp} = 8A			40	V
Off State Junction Capacitance	C _j	0 Vdc Bias f = 1MHz Between I/O pins and pin 2			50	pF

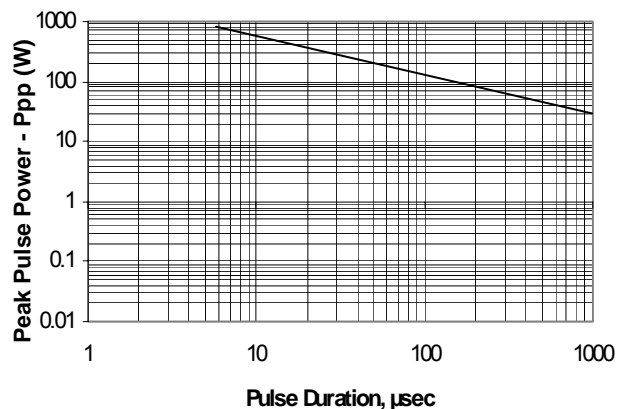


TYPICAL CHARACTERISTICS $T_J = 25^\circ\text{C}$ unless otherwise noted

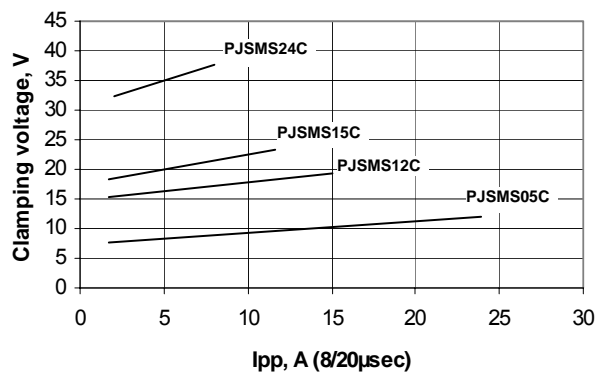
Surge Pulse Waveform Definition



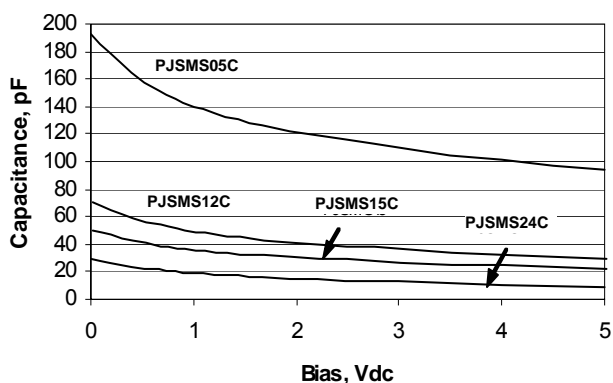
Non-Repetitive Peak Pulse Power vs Pulse Time



Clamping Voltage vs. Peak current



Off-State Capacitance per Device - 1MHz

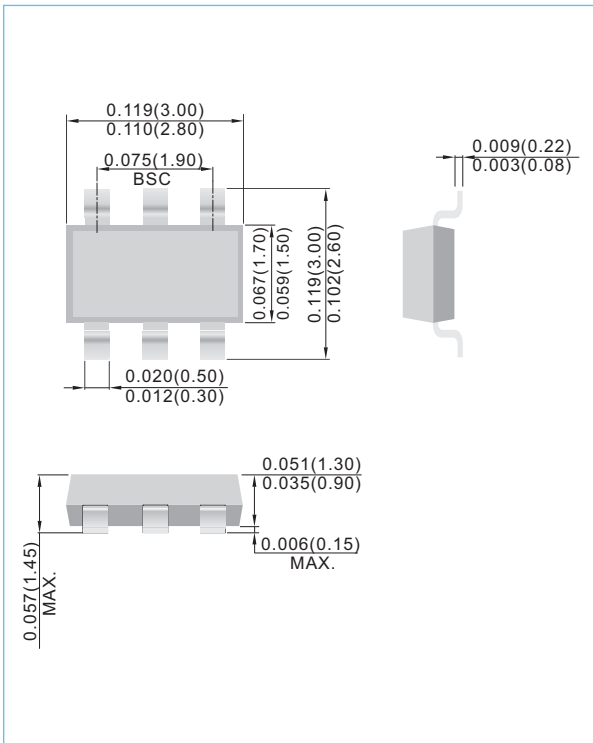




PACKAGE AND PAD LAYOUT DIMENSIONS

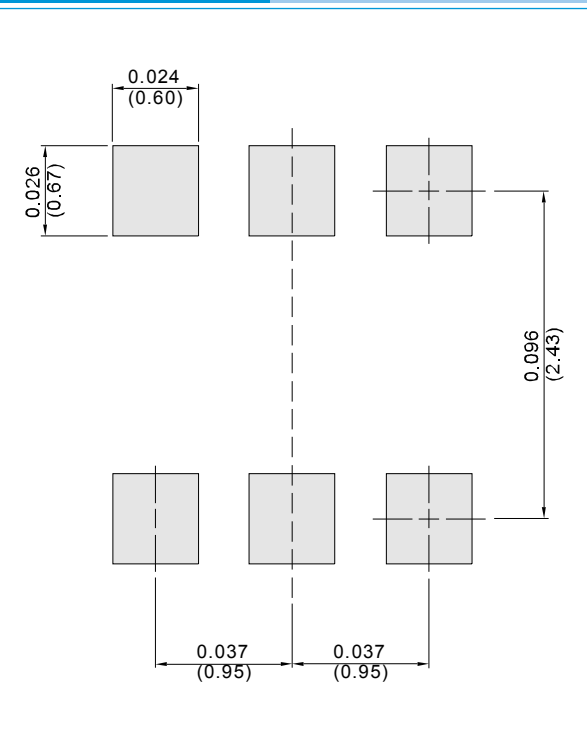
SOT23-6L

Unit : inch(mm)



SOT23-6L

Unit: inch (mm)



PJSMS05C SERIES

Part No_packing code_Version

PJSMS05C_R1_00001

PJSMS05C_R2_00001

For example :

RB500V-40_R2_00001

Part No.

Serial number

Version code means HF

Packing size code means 13"

Packing type means T/R

Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



PJSMS05C SERIES

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